# **SPDT RF Switch**

# **ZFSW2-33HDR-75+**

75Ω 5 to 3000 MHz High Power 3W

## **The Big Deal**

- High IP3, +70 dBm typ.
- High Power P0.1dB greater than 3W
- Low Insertion Loss, 0.5 dB at 1 GHz



CASE STYLE: QY2363

### **Product Overview**

ZFSW2-33HDR-75+ is a connector version of a high-power reflective SPDT RF switch, with reflective short on output ports in the OFF state. Made using a Silicon-on-Insulator process, it provides very high IP3 (+70 dBm typ.). This switch also has a built-in CMOS driver and negative voltage generator. ZFSW2 uses type -F female connectors for easy integration into 75 ohm test systems.

## **Key Features**

Feature	Advantages
High IIP3: +70 dBm typ.	Outstanding third order intercept perfomance makes this part ideal for use with high modulation signals such as digital CATV, QAM and other dense waveforms
Wideband operation, 5-3000 MHz	Enables a single component to be used in a vast array of applications DOCSYS 3.1, SATCOM system, automated test stations
Low Loss, 0.5 dB at 1 GHz & high input power, 3W	Low loss and high power capability enables a single switch to be used for a variety of applications, saving inventory.
Built-in negative voltage generator	Operates with single positive supply voltage; no need for DC blocking capacitors, unless external DC is present at the RF ports.
Built-in CMOS driver	No need for external driver. Simplifies use.

#### Notes

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# SPDT RF Switch

75Ω 5-3000 MHz

Reflective RF Switch with internal driver. Single Supply Voltage, +2.3V to +4.8V, High Power 3W

#### **Product Features**

- High IP3, +70 dBm typ. at 150 MHz
- High Power, P0.1dB 3W
- High Isolation, 41 dB typ. at 1 GHz
- Low insertion loss, 0.5 dB typ. at 1 GHz
- Low current consumption, 37 µA typ.



CASE STYLE: QY2363

# **ZFSW2-33HDR-75+**

+RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

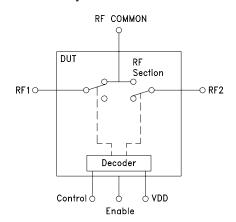
#### **Typical Applications**

- CATV systems
- SATCOM system
- Automated Test Stations

#### **General Description**

ZFSW2-33HDR-75+ is a high power (35 dBm) reflective SPDT switch with integral CMOS driver, operates with single positive supply voltage while consuming, 37µA typical. ZFSW2 is a reflective short on output port in OFF state. It has been designed for very wideband operation of 5-3000 MHz. ZFSW2 uses Type -F Female connectors for easy integration into 75 ohm test systems.

#### Simplified Schematic



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### RF Electrical Specifications, 5 - 3000 MHz, $T_{AMB}$ =25°C, $V_{DD}$ = +2.3 to 4.8V

Parameter	Condition (MHz)	Min.	Тур.	Max.	Units
Frequency Range		5		3000	MHz
	5 to 1000	_	0.5	0.65	
Insertion Loss	1000 to 1500	_	0.6	0.85	dB
(ON STATE)	1500 to 2000	_	0.85	1.15	ub
	2000 to 3000	_	0.95	1.30	
legat ID2 (V _ OV)	150	_	+70	_	dD.
Input IP3 (V <sub>DD</sub> =3V)	1800	_	+70	_	dBm
0.1dB Input Compression <sup>(1)</sup>	20 to 3000	_	35.0	_	dBm
	5 to 1000	39	42	_	dB
Isolation between RF Common and RF1/RF2 Ports	1000 to 1500	35	38	_	
isolation between RF Common and RF I/RF2 Ports	1500 to 2000	32	35	_	
	2000 to 3000	27	30	_	
	5 to 1000	40	45	_	
Indiation between DE4 and DE2 and (2)	1000 to 1500	35	41	_	dB
Isolation between RF1 and RF2 ports <sup>(2)</sup>	1500 to 2000	32	37	_	
	2000 to 3000	28	32	_	
	5 to 1000	_	21	_	dB
Datum Lana (ON OTATE) all anda	1000 to 1500	_	17	_	
Return Loss (ON STATE), all ports	1500 to 2000	_	15	_	
	2000 to 3000	_	16	_	

#### **DC Operating Electrical Specifications**

Parameter	Min.	Тур.	Max.	Units
VDD, Supply Voltage	2.3		4.8	V
Supply Current	_	37	_	μΑ
Control Enable Voltage Low	0	_	0.4	V
Control Enable Voltage High <sup>(3)</sup>	1.65	_	2.7	V
Control Current	_	1	_	μΑ
Shutdown mode - Supply Current	_	7	_	μΑ

#### Notes:

- 1. Do not exceed RF input power as shown in Absolute Maximum Rating table.
- 2. Enable voltage "HI", either RF1 or RF2 are ON.
  3. If V<sub>DD</sub> < 2.7, then Max Control Voltage High=V<sub>DD</sub>

#### **Switching Specifications**

Parameter	Min.	Тур.	Max.	Units
Rise/Fall Time (10 to 90% or 90 to 10% RF)	_	0.5 (Rise Time) 0.7 (Fall Time)	_	μSec
Switching Time, 50% CTRL to 90/10% RF	_	1.9 (ON Time) 1.1 (OFF Time)	_	μSec
Video Feedthrough, (control 0 to 1.65V, freq.=10 KHz)	_	3.0	_	mV <sub>P-P</sub>

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**Truth Table** (State of control and enable voltage selects the desired switch state)

State of:		RF Common to	
Control Voltage	Enable Voltage	RF1 RF2	
High	High	ON	OFF
Low	High	OFF ON	
Low/High	Low	Shutdown	

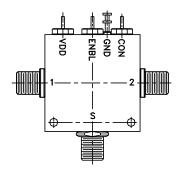
ON- low insertion loss state OFF- Isolation State

#### Absolute Maximum Ratings<sup>(6)</sup>

Parameter	Ratings
Operating Temperature	-40°C to +85°C
Storage Temperature	-55°C to 125°C
V <sub>DD</sub> , Supply Voltage	5.0V
Voltage Control	-0.2V Min. V <sub>DD</sub> Max.
RF input power	5 Watt <sup>7</sup>

<sup>6.</sup> Operation of this device above any of these conditions may cause permanent damage. 7. Derate linearly to 2.5W at  $85^{\circ}$ C.

## **Coaxial Configuration**

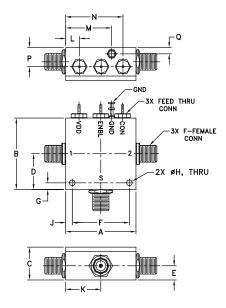


#### **Coaxial Connections**

Function	Port Number	Description
RF COM	S	RF Common/ SUM Port
RF1	1	RF Out #1/In Port #1
RF2	2	RF Out #2/In Port #2
Control	CON	CMOS Control IN
VDD	V <sub>DD</sub>	Supply Voltage
Enable	ENBL	Shutdown mode enabled by connecting to logic low
Ground	Case Ground and GND Pin	Ground Externally

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## **Outline Drawing (QY2363)**



#### Outline Dimensions (inch )

Н	G	F	Е	D	С	В	Α
.136	.15	1.312	.32	.81	.74	1.61	1.61
3.45	3.81	33.32	8.13	20.57	18.80	40.89	40.89
wt	Q	Р	N	М	L	K	J
grams	.14	.43	1.31	1.06	.31	.81	.15
65.0							

#### **Additional Detailed Technical Information**

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs

Case Style: QY2363

**Environmental Ratings: ENV75** 

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